

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IRFSL31N20D

G(1

3

1 2

D(2)

5(3)

pin 1, Oate

2, Drain

3, Source

FEATURES

- With To-262 package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

• ABSO	LUTE MAXIMUM RATINGS(Ta=25°C	TO-262 package		
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	200	V	
V _{GSS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-ContinuousTc=25℃ Tc=100℃	31 21	А	
I _{DM}	Drain Current-Single Pulsed	124	А	DIM MIN MAX
PD	Total Dissipation @Tc=25℃	200	W	A 4.37 4.77 A1 1.22 1.42 A2 2.47 2.87 b 0.70 0.97
T _{ch}	Max. Operating Junction Temperature	175	°C	b2 1.17 1.42 c 0.28 0.53 D 23.20 24.02
T _{stg}	Storage Temperature	-55~175	°C	D1 8.38 8.90 D2 6.00 - E 9.90 10.39 E4 7.30 -
• THER	MAL CHARACTERISTICS	e 2.54BSC G 1.25 1.50 H2 - 1.31		
SYMBOL	PARAMETER	МАХ	UNIT	L 13.34 14.10 L1 3.30 4.06 L3 0.95 1.15
Rth(ch-c)	Channel-to-case thermal resistance	1.05	°C/W	

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	200			v
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.5	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =18A			82	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V;Tj=25℃ V _{DS} =200V; V _{GS} = 0V;Tj=150℃			1 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =18A, V _{GS} = 0 V		1.0	1.3	V

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